

NOT RECOMMENDED FOR NEW DESIGN **CONTACT US**



DMN3115UDM

N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	RDS(ON) Max	I _D T _A = +25°C
	60mΩ @ V _{GS} = 4.5V	3.2A
30V	80mΩ @ V _{GS} = 2.5V	2.7A
	130mΩ @ V _{GS} = 1.5V	2.1A

Description

This new generation MOSFET has been designed to minimize the onstate resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

Applications

- General-purpose interfacing switches
- Power-management functions
- Analog switches

Features

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- **ESD Protected Gate**
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES™ DMN3115UDMQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

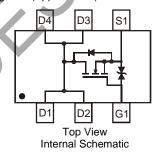
Mechanical Data

- Package: SOT26
- Package Material Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
 - Terminal Connections: See Diagram
- Weight: 0.015 grams (Approximate)





Top View

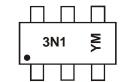


Ordering Information (Note 4)

Part Number	Package	Packing			
Part Number	Fackage	Qty.	Carrier		
DMN3115UDM-7	SOT26	3,000	Tape & Reel		
DMN3115UDMQ-7	SOT26	3,000	Tape & Reel		
DMN3115UDM-13	SOT26	10,000	Tape & Reel		
DMN3115UDMQ-13	SOT26	10,000	Tape & Reel		

- No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>
 For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



3N1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: K = 2023)M = Month (ex: 1 = January)

Date Code Key

Year	2007		2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	U		K	L	М	N	0	Р	R	S	T	J
				A		1	11	Aug	Sep	Oot	Nov	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	ъeр	Oct	NOV	Dec



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	VDSS	30	V
Gate-Source Voltage	V _{GSS}	±8	V
Drain Current (Note 5)	ID	3.2	А
Pulsed Drain Current (Note 5)	I _{DM}	12.8	А

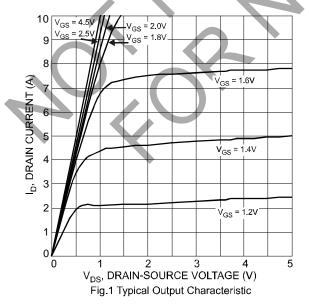
Thermal Characteristics

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	P _D	900	mW
Thermal Resistance, Junction to Ambient	RөJA	139	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

	T		_			3 4 111
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS} 《	30	_	P —	V	$V_{GS} = 0V$, $I_{D} = 100\mu A$
Zero Gate Voltage Drain Current	IDSS)	1	μΑ	$V_{DS} = 30V$, $V_{GS} = 0V$
Gate-Source Leakage	IGSS	1		±5	μΑ	$V_{GS} = \pm 8V$, $V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)				4		
Gate Threshold Voltage	V _{GS(TH)}	0.5		1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
			40	60		$V_{GS} = 4.5V, I_{D} = 6A$
Static Drain-Source On-Resistance	RDS(ON)		50	80	mΩ	V _G S = 2.5V, I _D = 2A
			76	130		V _{GS} = 1.5V, I _D = 1.0A
Forward Transfer Admittance	Y _{fs}	1	8	Ť	S	V _{DS} = 10V, I _D = 6A
Diode Forward Voltage (Note 6)	V _{SD}		0.7	1.1	V	$V_{GS} = 0V$, $I_S = 2A$
DYNAMIC CHARACTERISTICS						
Input Capacitance	Ciss		476	_	pF	451/1/ 01/
Output Capacitance		4	77	_	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	-	59	_	pF	I = I.OIVII IZ

5. Device mounted on FR-4 PCB, minimum recommended pad layout on 2oz. Copper pads. 6. Short duration pulse test used to minimize self-heating effect. Notes:



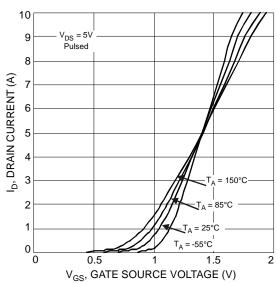


Fig. 2 Typical Transfer Characteristics



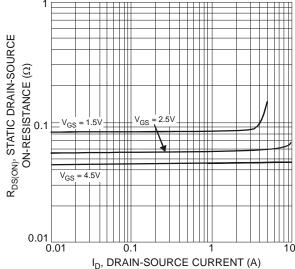
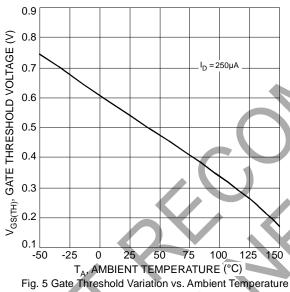


Fig. 3 On-Resistance vs. Drain Current & Gate Voltage



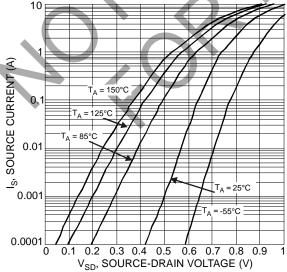
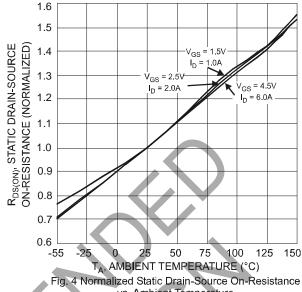
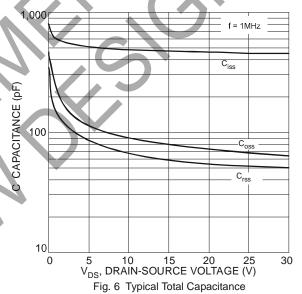


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage



vs. Ambient Temperature

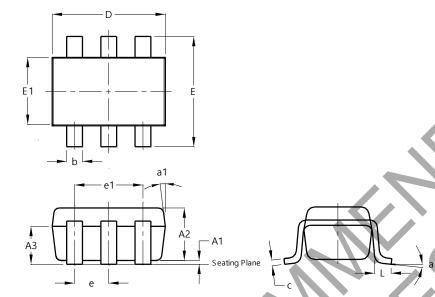




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT26

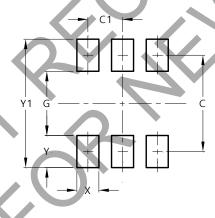


SOT26							
Dim	Min	Max	Тур				
A1	0.013	0.10	0.05				
A2	1.00	1.30	1.10				
A3	0.70	0.80	0.75				
b	0.35	0.50	0.38				
C	0.10	0.20	0.15				
D	2.90	3.10	3.00				
е	-	-	0.95				
e1	-		1.90				
ш	2.70	3.00	2.80				
E1	1.50	1.70	1.60				
L	0.35	0.55	0.40				
а	- 1		8°				
a1		-	7°				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Υ	0.80
Y1	3.20



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